

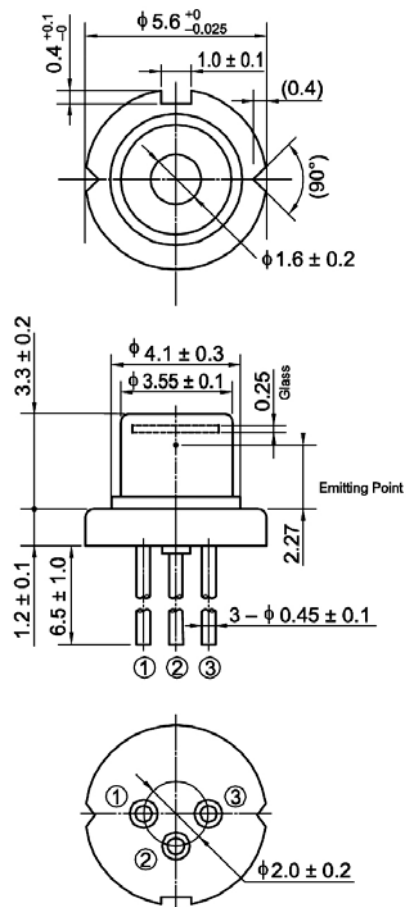
# Data Sheet

# HL6385DG

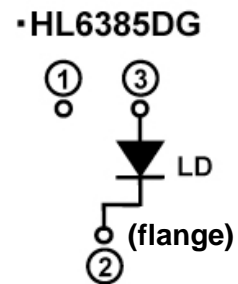
642nm / 150mW AlGaInP Laser Diode

USHIO

## Outline



## Internal Circuit



(unit:mm)

## Features

- Visible light output: 642nm Typ.
- Optical output power: 150mW (CW)
- Single transverse mode
- Operating temperature: +40°C
- Small package:  $\phi 5.6$ mm
- TE mode oscillation

## Application

- Laser module
- Light source of optical equipments

## Absolute Maximum Ratings (Tc=25°C)

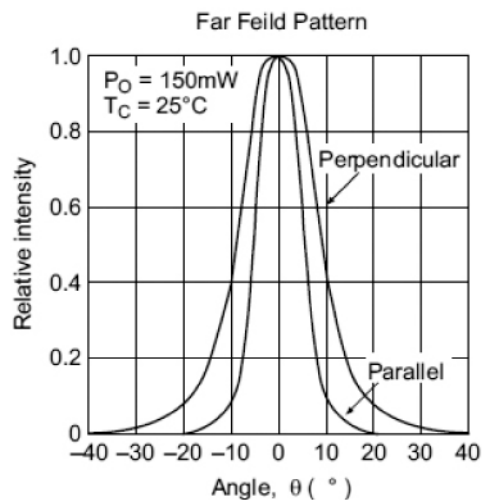
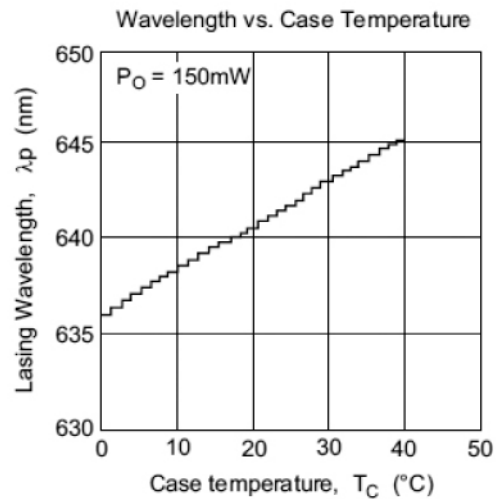
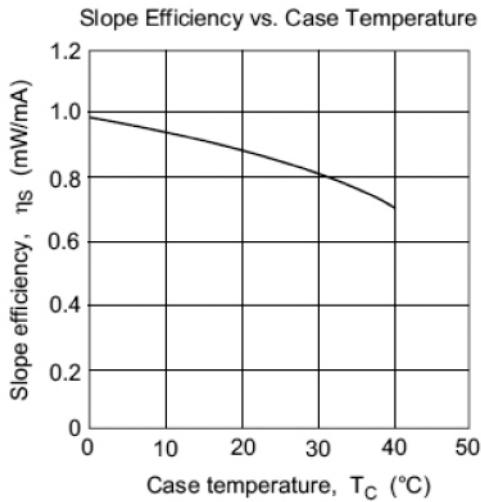
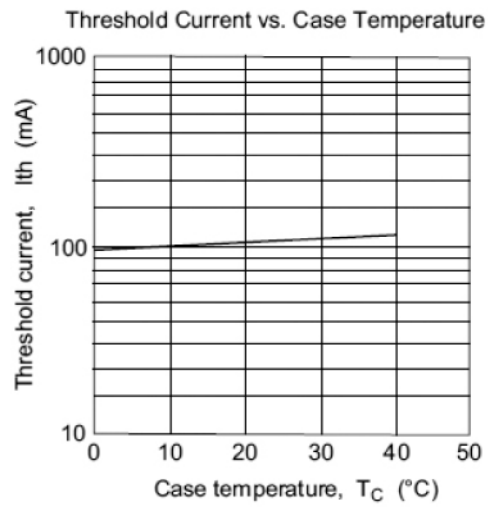
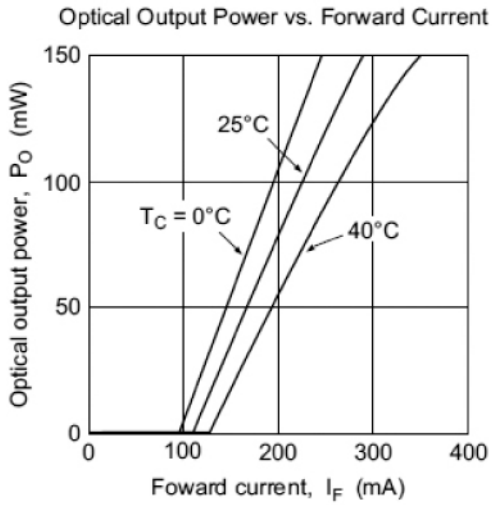
Item	Symbol	Ratings	Unit
Optical output power	Po	150	mW
LD Reverse Voltage	V <sub>R(LD)</sub>	2	V
Operating Temperature	Topr	-10 ~ +40	°C
Storage Temperature	Tstg	-40 ~ +85	°C

Note: Operating temperature is defined by Case temperature "Tc". High increase in temperature of LD chip itself is expected during operation due to high current density. Thus, without proper heat dissipation, it is observed that no specific output power is achieved or it results to LD degradation. It is advised that sufficient measure of heat dissipation should be taken so that LD's maximum operating temperature is not exceeded during actual operation.

## Optical and Electrical Characteristics (Tc=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Threshold current	I <sub>th</sub>	-	110	140	mA	-
Operating current	I <sub>op</sub>	-	280	350	mA	Po=150mW
Operating voltage	V <sub>op</sub>	-	2.6	3.0	V	Po=150mW
Beam divergence Parallel to the junction	θ <sub>//</sub>	6	9	13	°	Po=150mW, FWHM
Beam divergence Perpendicular to the junction	θ <sub>⊥</sub>	13	17	22	°	Po=150mW, FWHM
Lasing Wavelength	λ <sub>p</sub>	635	642	647	nm	Po=150mW

## Typical Characteristic Curves



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